

# **CBM-120**

# **Mosaic Array Series**

# **Ultraviolet Chip On Board LEDs**





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## **Features:**

- Mosaic Array UV LED chipset with surface emitting area of 12 mm<sup>2</sup>, 4:3 aspect ratio
- All the benefits of chip on board processing without the need for complicated assembly process
- Vertical chip UV LED technology for high power density and uniform emission
- Wide Range of UVA Wavelengths
- High thermal conductivity copper coreboard package
- Low-profile window for efficient coupling into small-etendue systems
- Can be operated at variable drive currents up to 18A
- NIST traceable optical and electrical measurement testing
- Environmentally friendly: RoHS and Halogen compliant

## **Applications:**

- Curing:
  - > Inks
  - > Coatings
  - > Adhesives
- Inspection
- Machine Vision

- Fiber-coupled illumination
- Specialty Projection Systems for Maskless Lithography
- Rapid Prototyping and 3D printing
- Medical and Scientific Instrumentation





## **Technology Overview**

Luminus LEDs benefit from innovations in device technology, chip packaging and thermal management. This suite of technologies give engineers and system designers the freedom to develop solutions both high in power and efficiency.

#### **Luminus Mosaic Array LED Technology**

Luminus' Devices vertical chip technology enables LED chips with uniform brightness over the entire chip surface. The optical power and brightness produced by these densely packed arrays of devices enable solutions not possible with single chip packages that be used to replace arc and halogen lamps.

#### **Packaging Technology**

Thermal management is critical in high power LED applications. With a thermal resistance from junction to heat sink of 0.6 °C/W, Luminus CBM-120 LEDs have the lowest thermal resistance of any UV LED on the market. This will allow the LEDs to be driven at higher current densities while maintaining a low junction temperature, thereby resulting in brighter solutions and longer lifetimes.

#### Reliability

With designs based on years of chip and packaging development experience, Luminus LEDs are one of the most reliable light sources in the world today. Luminus LEDs pass a rigorous suite of environmental and mechanical stress tests, including mechanical shock, vibration, temperature cycling and humidity, and have been fully qualified for use in extreme high power and high current applications. With very low failure rates and median lifetimes that can exceed 30,000 hours, Luminus UV LEDs are ready for even the most demanding applications.

#### **Environmental Benefits**

Luminus LEDs help reduce power consumption and the amount of hazardous waste entering the environment. All LED products manufactured by Luminus are RoHS and Halogen compliant and free of hazardous materials, including lead and mercury.

## **Understanding Mosaic Array UV LED Test Specifications**

Every Luminus LED is fully tested to ensure that it meets the high quality standards expected from Luminus' products.

#### **Testing Temperature**

Luminus core board products are typically measured in such a way that the characteristics reported agree with how the devices will actually perform when incorporated into a system. This measurement is accomplished by mounting the devices on a 40°C heat sink and measuring the device while fully powered.

This method of measurement ensures that Luminus LEDs perform in the field just as they are specified.

#### **Multiple Operating Points**

The tables on the following pages provide typical optical and electrical characteristics for the standard drive conditions. Since the LEDs can be operated over a wide range of drive conditions (currents from 200 mA to 18 A, and duty cycle from <1% to 100%) there are many other potential values attainable. Driving devices beyond recommended driving conditions shortens lifetime.



# **Ordering Information**

Products	Ordering Part Number	Description
CDM 120 UV	CBM-120-UV-C31-FF###-2#	CBM-120 Mosaic Array UV chipset consisting of 12x1mm2 UV LEDs, a thermistor, connectors, and a square copper-core PCB.
CBM-120-UV	CBM-120-UV-C14-FF###-2#	CBM-120 Mosaic Array UV chipset consisting of 12x1mm2 UV LEDs, connectors, and a slim (rectangular) copper-core PCB.

## **Part Number Nomenclature**

CBM — 120 — CC — C## — FF###-2#

Product Family	Chip Area	Color	Package Configuration	Bin Kit 1,2
CBM: Copper- core PCB, Mosiac Array	120: 12 mm²	UV = Ultraviolet	C14: 44.5 mm x 10 mm - Slim Package C31: 28 mm x 26.75 mm - Square Package See Mechanical Drawing section	See page 5 for complete bin definition table

Note 1: A Bin Kit represents a group of individual flux or power bins that are shippable for a given ordering part number. Individual flux bins are not orderable..

Note 2: Flux Bin listed is minimum bin shipped - higher bins may be included at Luminus' discretion



## **CBM-120-UV Binning Structure**

CBM-120-UV LEDs are specified for luminous flux and chromaticity/wavelength at a drive current of 9 A (750 mA/mm2) and placed into one of the following Power Bins and Wavelength Bins:

#### Power Bins<sup>3</sup>

Color	Power Flux Bin (FF)	Minimum Flux (W)	Maximum Flux (W)
	FA	6.0	6.5
	FB	6.5	7.0
	GA	7.0	7.5
	GB	7.5	8.0
UV	Н	8.0	9.1
	I	9.1	10.0
	J	10.0	11.0
	K	11.0	12.1
	Ĺ	12.1	13.3

Note 3: Luminus maintains a +/- 6% tolerance on power measurements.

## **Peak Wavelength Bins**

Color	Wavelength Bin (###)	Minimum Wavelength (nm)	Maximum Wavelength (nm)
	365	365	370
	370	370	375
UV	375	375	380
	380	380	385
	385	385	390
	390	390	395
	395	395	400
	400	400	405
	405	405	410



# **CBM-120 UV Mosaic Array Bin Kits**

	Lumino	ous Flux		Ordering
Wavelength Range	/avelength Range Bin Kit Flux Min. Flux Code		Wavelength Bins	Bin Kit Number
	FA	6.0	365	FA365-21
	FA	6.0	365, 370	FA365-22
	FB	6.5	365	FB365-21
365-375	ГВ	0.5	365, 370	FB365-22
303-373	GB	7.7	365	GB365-21
	GB	7.7	365, 370	GB365-22
	Н	8.0	365	H365-21
	П	6.0	365, 370	H365-22
			380	K380-21
	К	11.0	385	K385-21
200 200			380, 385	K380-22
380-390	L		380	L380-21
		12.1	385	L385-21
			380, 385	L380-22
	K 11		390	K390-21
		11.0	395	K395-21
390-400			390, 395	K390-22
390-400			390	L390-21
	L	12.1	395	L395-21
			390, 395	L390-22
			400	K400-21
	К	11.0	405	K405-21
400-410			400, 405	K400-22
400-410			400	L400-21
	L	L 12.1	405	L405-21
			400, 405	L400-22



# Reference Optical & Electrical Characteristics ( $T_{hs} = 40$ °C) <sup>4,5</sup>

UV									
Parameter	Symbol		Values <sup>6</sup>						Unit
Peak Wavelength Range	λ	365 - 375	380-	-390	390	-400	400-	-410	nm
Drive Conditions 7	1	9.0	9	9.0 9.0		9.0		Α	
Peak Wavelength Typ.	$\lambda_{_{p}}$	368	384	387	393	397	403	407	nm
Current Density	j	0.75	0.75		0.75		0.75		A/mm²
	$V_{_{Fmin}}$	3.0	3	.0	3	.0	3.	.0	V
Forward Voltage	$V_{_F}$	3.6	3	.6	3	.6	3.	.6	V
	V <sub>F max</sub> 4.0 4.0 4.0		4.0		V				
Radiometric Flux 8	$oldsymbol{\Phi}_{_{typ}}$	8.5	11.5		11.5 11.5		11	.5	W
FWHM at 50% of Φ	Δλ <sub>1/2</sub>	14	1	4	1	4	1	4	nm

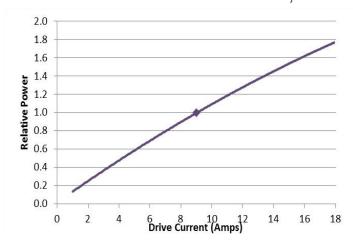
Parameter	Symbol	Values	Unit
Absolute Minimum Current (CW or Pulsed) 9		0.2	Α
Absolute Maximum Current (CW) 10		365nm - 12 380nm-410nm - 18	А
Absolute Maximum Surge Current <sup>10</sup> (Frequency > 240 Hz, duty cycle =10%, t=1ms)		30	А
Maximum Junction Temperature 11	$T_{jmax}$	100	°C
Storage Temperature Range		-40 to +100	°C
Emitting Area		12.9	mm²
Emitting Area Dimensions		4.50 × 3.32	mm × mm

- Note 4: Data verified using NIST traceable calibration standard.
- Note 5: All data are based on test conditions with a constant heat sink temperature  $T_{hs} = 40^{\circ}$ C under pulse testing conditions. Pulse conditions: 25% duty-cycle, frequency of 720Hz, 3 second soak.
- Note 6: Unless otherwise noted, values listed are typical. Devices are production tested and specified at 9 A.
- Note 7: Listed drive conditions are typical for common applications. CBM120-UV devices can be driven at currents ranging from 200 mA to 12A-18 A and at duty cycles ranging from 1% to 100%. Drive current and duty cycle should be adjusted as necessary to maintain the junction temperature desired to meet application lifetime requirements.
- Note 8: Typical total flux from emitting area at listed peak wavelength. Reported performance is included to show trends for a selected power level. For specific minimum and maximum values, use bin tables. For product roadmap and future performance of devices, contact Luminus.
- Note 9: Special design considerations must be observed for operation under 1 A. Please contact Luminus for further information.
- Note 10: CBM-120-UV LEDs are designed for operation to an absolute maximum current as specified above. Product lifetime data is specified at recommended forward drive currents. Sustained operation at or beyond absolute maximum currents will result in a reduction of device life time compared to recommended forward drive currents. Actual device lifetimes will also depend on junction temperature. Refer to the lifetime derating curves for further information. In pulsed operation, rise time from 10-90% of forward current should be longer than 0.5 µseconds.
- Note 11: Lifetime dependent on LED junction temperature. Input power and thermal system must be properly managed to ensure lifetime.

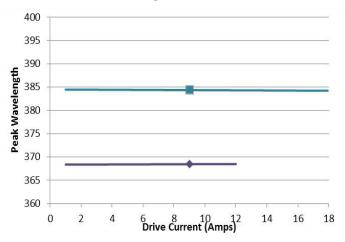


## **Optical & Electrical Characteristics**

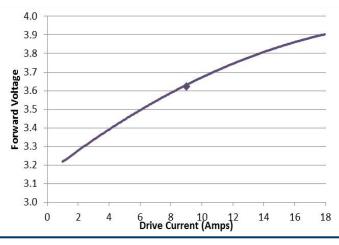
# Relative Power vs Forward Current, $T_1 = 60$ °C



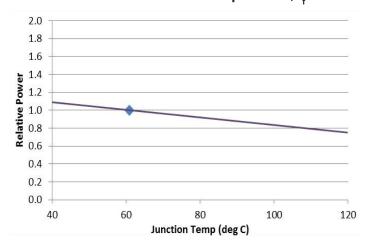
## **Peak Wavelength vs Forward Current**



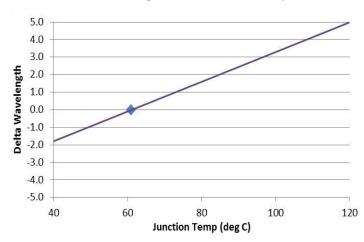
## **Forward Voltage vs Forward Current**



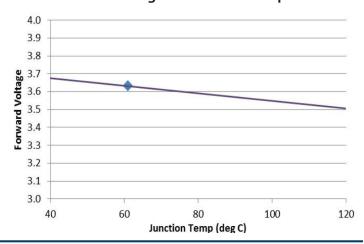
## Relative Power vs Junc. Temperature, $I_r = 9 \text{ A}$



## **Peak Wavelength vs Junction Temperature**

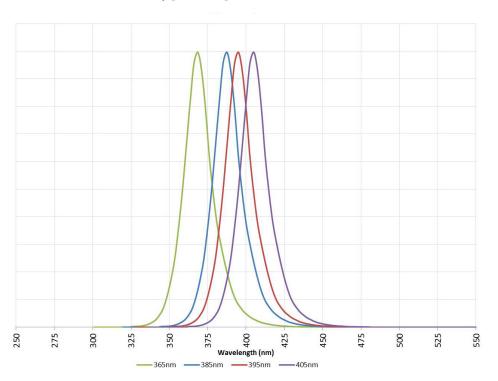


#### Forward Voltage vs Junction Temperature

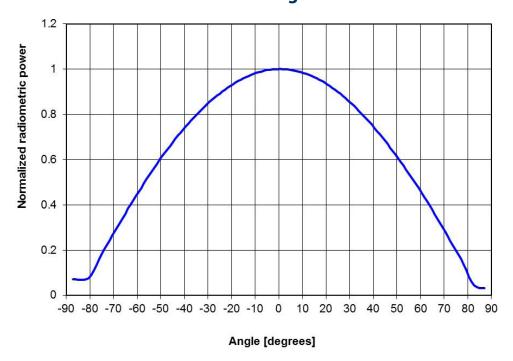




# Typical Spectrum 12



# Emission Angle 13

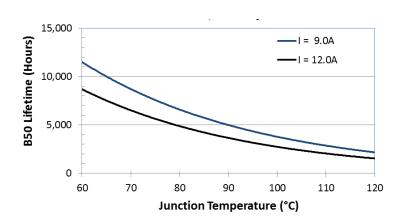


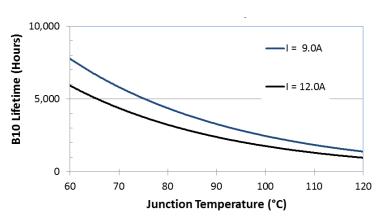
Note 12: Typical spectrum at current of 9 A in continuous operation.

Note 13: Detailed information on emission including ray trace files can be found at: http://www.luminus.com/resource/design.html

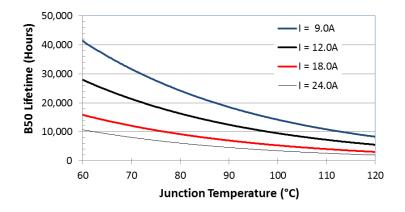


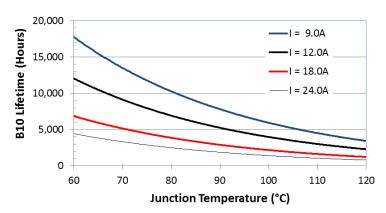
## Reliability Data - 365nm





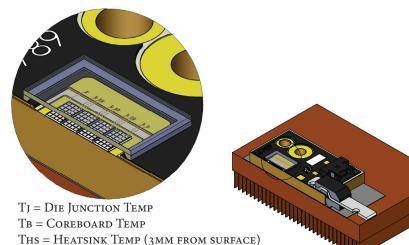
## Reliability Data - 380nm-410nm







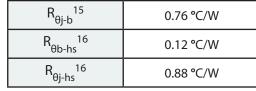
#### Thermal Resistance CBM-120-UV

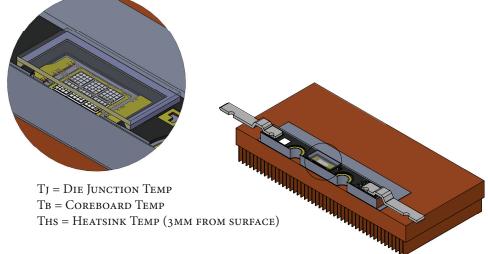


#### Typical Thermal Resistance 14 - C31

R <sub>θj-b</sub> <sup>15</sup>	0.61 °C/W
R <sub>0b-hs</sub> 16	0.12 °C/W
R <sub>θj-hs</sub> 16	0.73 °C/W
R <sub>θj-ref</sub> <sup>15</sup>	0.64 °C/W

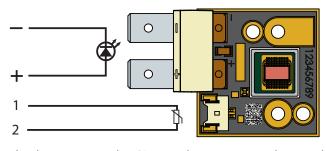
# Tref - Thermistor Temp Typical Thermal Resistance 14 - C14

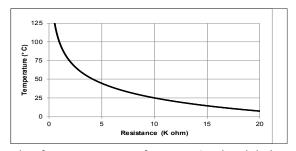




- Note 14: Real thermal resistance data "Electrical" thermal resistance values available upon request
- Note 15: Thermal resistance values are based on measured wavelength shift data.
- Note 16: Thermal Resistance is based on eGraf 1205 Thermal interface.

# **Electrical Pinout - C31 Package**



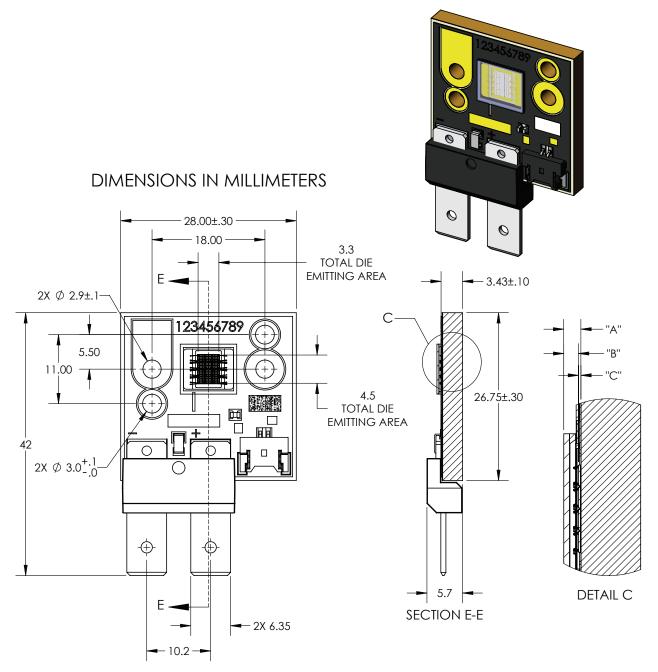


The thermistor used in CBT-120 devices mounted on coreboards is from Murata Manufacturing Co. The global part number is NCP18XH103J03RB. Please see http://www.murata.com/ for details on calculating thermistor temperature.

For more information on use of the thermistor, please contact Luminus directly.



## Mechanical Dimensions - CBM-120-UV-C31 Mosaic Array LED Emitter



DIMENSION NAME	DESCRIPTION	NOMINAL DIMENSION	TOLERANCE
"A"	TOP OF METAL SUBSTRATE TO TOP OF WINDOW	.91	±.13
"B"	TOP OF DIE EMITTING AREA TO TOP OF WINDOW	.78	±.11
"C"	TOP OF METAL SUBSTRATE TO TOP OF DIE EMITTING AREA	.13	±.02

DWG-002558

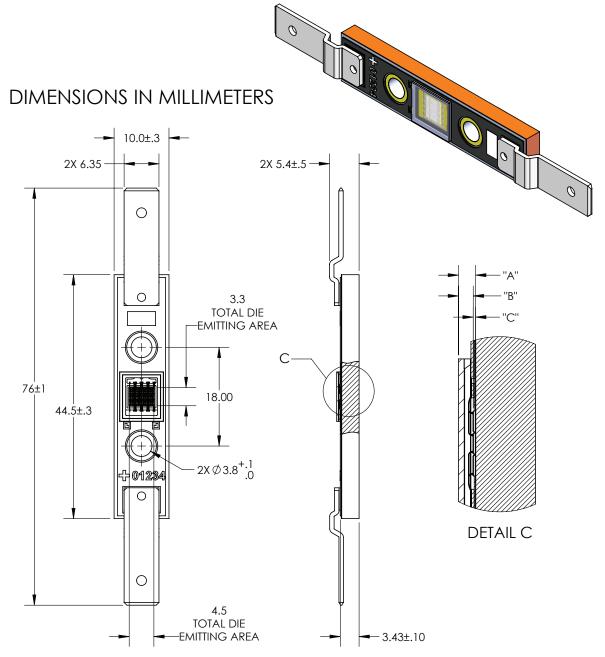
Recommended connector for Anode and Cathode: Panduit Disco Lok<sup>™</sup> Series P/N: DNG14-250FL-C. Thermistor Connector: MOLEX P/N 53780-0270 or GCT P/N WTB08-021S-F.

Recommended Female: MOLEX P/N 51146-0200, GCT P/N WTB06-021S-F or equivalent

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# Mechanical Dimensions - CBM-120-UV-C14 Mosaic Array LED Emitter



DIMENSION NAME	DESCRIPTION	NOMINAL DIMENSION	TOLERANCE
"A"	TOP OF METAL SUBSTRATE TO TOP OF WINDOW	.91	±.13
"B"	TOP OF DIE EMITTING AREA TO TOP OF WINDOW	.78	±.11
"C"	TOP OF METAL SUBSTRATE TO TOP OF DIE EMITTING AREA	.13	±.02

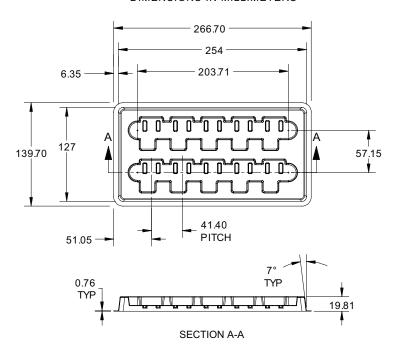
DWG-002534

Recommended connector for Anode and Cathode: Panduit Disco Lok™ Series P/N: DNG14-250FL-C.



# **Shipping Tray Outline - CBM-120-C31**

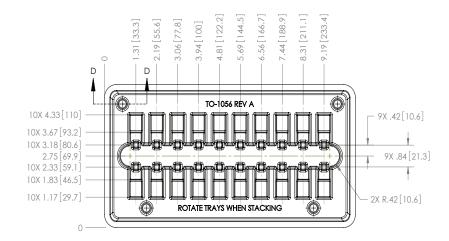
#### **DIMENSIONS IN MILLIMETERS**

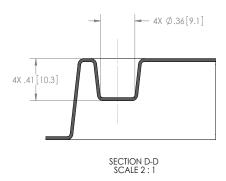


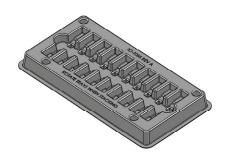




# **Shipping Tray Outline - CBM-120-C14**









## **Packing and Shipping Specification (CBM-120)**

#### **Packing Specification**

Packing Configuration	Qty /Pack	Box Dimensions (diameter x W, mm)	Gross Weight (kg)
Stack of 5 trays with 10 devices per tray Each pack is enclosed in ESD bag	50	140 x 280 x 70	2.7

#### **Product Label Specification**

#### Label Fields (subject to change):

- 6-8 digit Box number (for Luminus internal use)
- Luminus ordering part number
- Quantity of devices in pack
- Part number revision (for Luminus internal use)
- Customer's part number (optional)
- Flux Bin
- 2D Bar code





Sample label –for illustration only

## **Shipping Box**

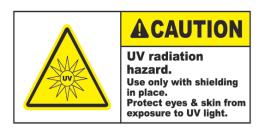
Shipping Box	Quantity	Material	Dimensions (L x W x H, mm)
Carton Box	1 -20 packs (50 - 1000 Devices)	S4651	560 x 560 x 200





## **History of Changes**

Rev	Date	Description of Change	
Α	01/09/2015	Initial Release - Preliminary Specifications for 365nm and 380nm CBM-120 Parts	
В	03/20/2015	Added Data for 390nm and 400nm CBM-120 Parts, Updated binning structure	
01	05/31/2015	Updated Binning, Added Angular Distribution Data, Added Reliability Data	
02	09/18/2015	Updated Binning	
03	03/29/2016	Updated Binning	



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